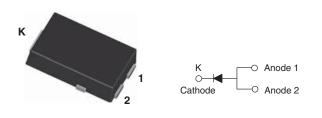
Vishay Semiconductors

Ultrafast Rectifier, 6 A FRED Pt[®]



www.vishay.com

TO-277A (SMPC)

PRODUCT SUMMARY						
Package	TO-277A (SMPC)					
I _{F(AV)}	6 A					
V _R	600 V					
V _F at I _F	1.3 V					
t _{rr} (typ.)	42 ns					
T _J max.	175 °C					
Diode variation	Single die					

FEATURES

- Ultrafast recovery time, reduced Qrr, and soft recovery
- 175 °C maximum operating junction temperature
- For PFC, CRM snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 gualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

State of the art ultrafast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, lighting, in the AC/DC section of SMPS, freewheeling and clamp diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Peak repetitive reverse voltage	V _{RRM}		600	V			
Average rectified forward current	I _{F(AV)}	T _{Sp} = 150 °C	6	А			
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	120	A			
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 $^{\circ}$ C unless otherwise specified)						
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS		TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-	
Forward voltage	N	I _F = 6 A	-	1.10	1.30	V
Forward voltage	vard voltage V _F		-	0.95	1.15	
		$V_{R} = V_{R}$ rated	-	-	5	
Reverse leakage current I _R		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	25	150	μA
Junction capacitance	CT	V _R = 600 V	-	8	-	pF

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RoHS COMPLIANT

HALOGEN FREE



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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 $^{\circ}$ C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS	
			Α/μs, V _R = 30 V	-	42	-	ns	
Povoroo rocovoru timo	+	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		-	-	60		
Reverse recovery time t _{rr}	T _J = 25 °C		-	58	-			
		T _J = 125 °C		-	85	-		
Dook roooyony ourront		T _J = 25 °C	$I_F = 6 A$	-	10	-	А	
Peak recovery current I _{RRM}	T _J = 125 °C	dl _F /dt = 500 A/µs V _R = 400 V	-	15	-	~		
Reverse recovery charge Q _{rr}	0	T _J = 25 °C		-	290	-	nC	
	T _J = 125 °C		-	620	-	nu		

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C
Thermal resistance, junction to solder pad	R _{thJ-Sp}		-	2.4	3.5	°C/W
Approximate weight				0.1		g
				0.0035		oz.
Marking device		Case style TO-277A (SMPC)		NE	:U6	

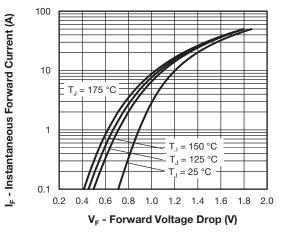


Fig. 1 - Typical Forward Voltage Drop Characteristics

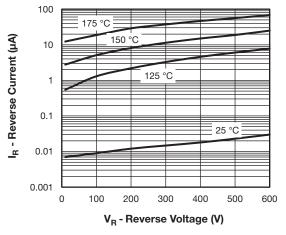


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

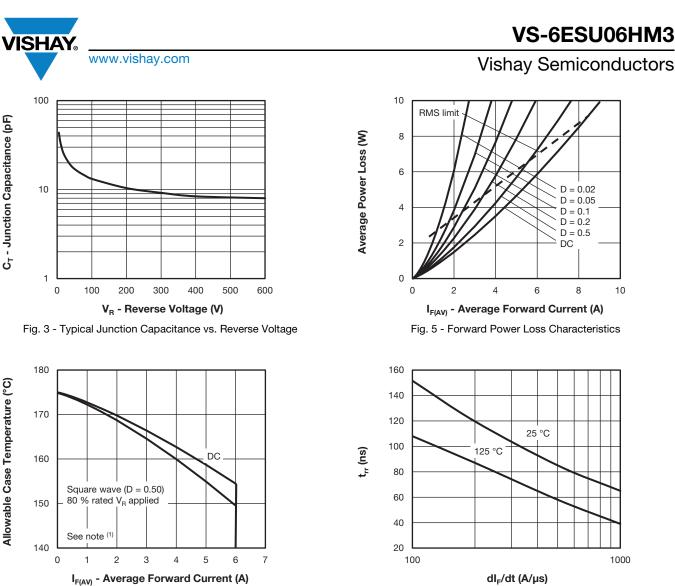
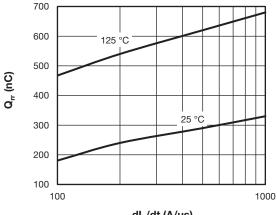


Fig. 4 - Maximum Allowable Case Temperature

vs. Average Forward Current





dl_F/dt (A/µs)



Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{5}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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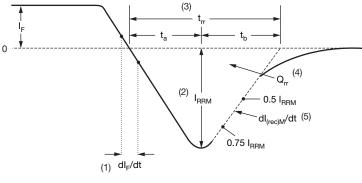
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VS-6ESU06HM3

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- (1) dl_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.

(4) Q_{rr} - area under curve defined by t_{rr} and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

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(5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 8 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

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Device code	VS-	6	Е	S	U	06	н	М3
		2	3	4	5	6	7	8
	1 .	- Vis	nay Sen	niconduc	ctors pro	oduct		
	2 -	- Cur	rent rati	ng (6 =	6 A)			
	3 -	· Circ	cuit conf	iguratior	า:			
		E =	single c	liode				
	4 -	- S =	SMPC	package)			
	5 -	· Pro	cess typ	e,				
		U =	ultrafas	t recove	ery			
	6 -	· Vol	tage coo	le (06 =	600 V)			
	7 -	• H=	AEC-Q	101 qua	lified			
	8 -	• M3	= halog	en-free,	RoHS-0	complia	nt, and	termina

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-6ESU06HM3/86A	1500	1500	7" diameter plastic tape and reel				
VS-6ESU06HM3/87A	6500	6500	13" diameter plastic tape and reel				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95570				
Part marking information	www.vishay.com/doc?95565				
Packaging information	www.vishay.com/doc?88869				

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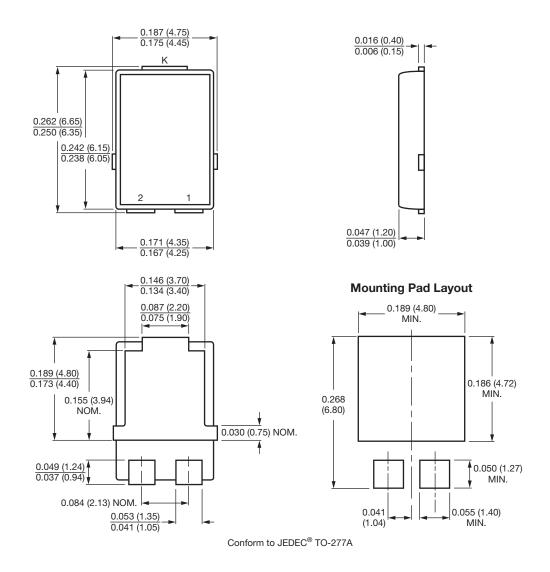
Outline Dimensions





TO-277A (SMPC)

DIMENSIONS in inches (millimeters)





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